Triple 3-input NAND gate Rev. 3 — 5 August 2016

Product data sheet

#### 1. **General description**

The 74HC10; 74HCT10 is a triple 3-input NAND gate. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

#### **Features and benefits** 2.

- Complies with JEDEC standard JESD7A
- Input levels:
  - For74HC10: CMOS level
  - For 74HCT10: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

#### **Ordering information** 3.

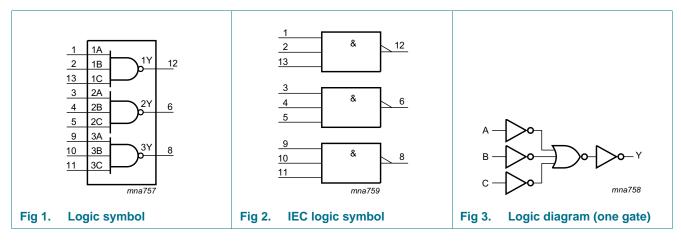
#### Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC10D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HCT10D				
74HC10DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads;	SOT337-1
74HCT10DB			body width 5.3 mm	
74HC10PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1
74HCT10PW			body width 4.4 mm	

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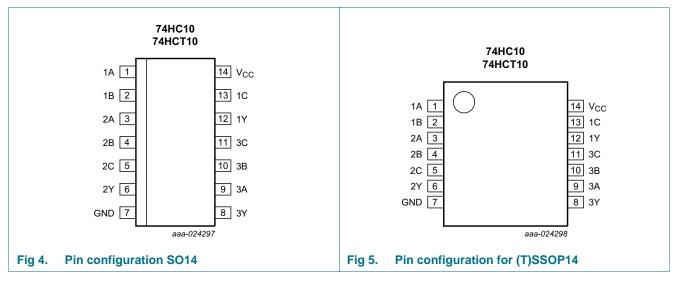
**Triple 3-input NAND gate** 

## 4. Functional diagram



### 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2.   Pin description						
Symbol	Pin	Description				
1A, 2A, 3A	1, 3, 9	data input				
1B, 2B, 3B	2, 4, 10	data input				
GND	7	ground (0 V)				
1C, 2C, 3C	13, 5, 11	data input				
1Y, 2Y, 3Y	12, 6, 8	data output				
V <sub>cc</sub>	14	supply voltage				

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### 6. Functional description

Table 3.	Function selection	n[1]		
Input		Output		
nA		nB	nC	nY
L		Х	Х	Н
Х		L	Х	Н
Х		Х	L	Н
Н		Н	Н	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care

### 7. Limiting values

### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I}$ < -0.5 V or $V_{I}$ > $V_{CC}$ + 0.5 V	<u>[1]</u>	-	±20	mA
I <sub>ОК</sub>	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u>	-	±20	mA
I <sub>O</sub>	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO14 and (T)SSOP14	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60  $^\circ\text{C}.$ 

### 8. Recommended operating conditions

### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter Conditions		74HC10			74HCT			Unit
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

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### 9. Static characteristics

### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC10	1	1								
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
	V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V	
VIL	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
	$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O}$ = -5.2 mA; $V_{CC}$ = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC} \text{ or GND};$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current		-	-	2.0	-	20	-	40	μΑ
CI	input capacitance		-	3.5	-	-	-	-	-	pF

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Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT1	D									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
	I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V	
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 4 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0.15	0.26	-	0.33	-	0.4	V
lı	input leakage current		-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	2.0	-	20	-	40	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	150	540	-	675	-	735	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

### Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

### **10. Dynamic characteristics**

### Table 7. Dynamic characteristics

 $GND = 0 V; C_L = 50 pF;$  for test circuit, see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Conditions		25 °C		–40 °C to +125 °C		Unit
				Min	Тур	Мах	Max (85 °C)	Max (125 °C)	
74HC10		·							
t <sub>pd</sub> propagation delay		nA, nB to nY; see <u>Figure 6</u>	<u>[1]</u>						
		V <sub>CC</sub> = 2.0 V		-	30	95	120	145	ns
	$V_{CC} = 4.5 V$		-	11	19	24	29	ns	
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	9	-	-	-	ns
		$V_{\rm CC} = 6.0 \ V$		-	9	16	20	25	ns
t <sub>t</sub>	transition time	see <u>Figure 6</u>	[2]						
		V <sub>CC</sub> = 2.0 V		-	19	75	95	110	ns
		$V_{CC} = 4.5 V$		-	7	15	19	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	13	16	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$	<u>[3]</u>	-	12	-	-	-	pF

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Symbol Parameter Conditio		Conditions		25 °C			-40 °C to	Unit	
			Min		Тур	Max	Max (85 °C)	Max (125 °C)	_
74HCT10	)	1							
t <sub>pd</sub>	propagation delay	nA, nB to nY; see Figure 6	<u>[1]</u>						
		V <sub>CC</sub> = 4.5 V		-	14	24	30	36	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	11	-	-	-	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>	[2]	-	7	15	19	22	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V	<u>[3]</u>	-	14	-	-	-	pF

#### **Table 7. Dynamic characteristics** ... continued GND = 0 V: $C_{i} = 50$ pF: for test circuit, see Figure 7.

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$ 

- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D}$  =  $C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N$  +  $\sum$  ( $C_{L} \times V_{CC}{}^{2} \times f_{o}$ ) where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

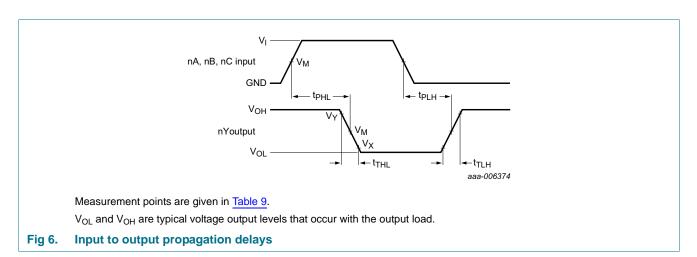
 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of outputs.

### 11. Waveforms



### Table 8. Measurement points

Туре	Input	Output			
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
74HC10	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>	
74HCT10	1.3 V	1.3 V	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>	

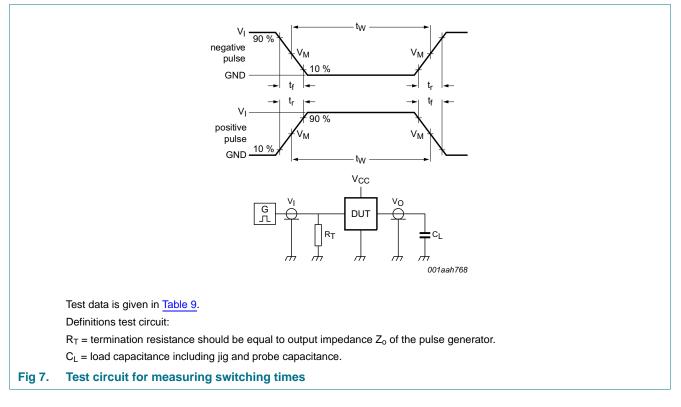
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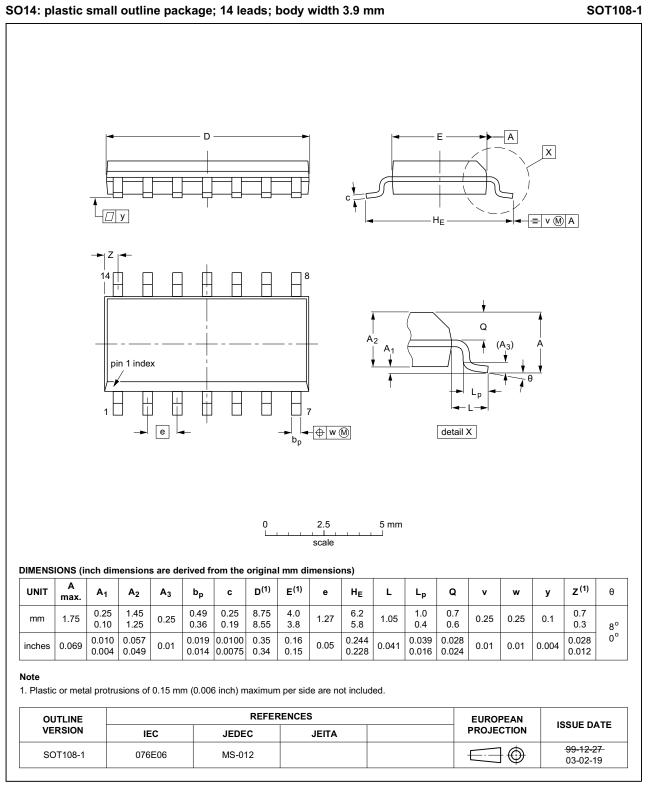


#### Table 9. Test data

Туре	Input L		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC10	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74HCT10	3.0 V	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

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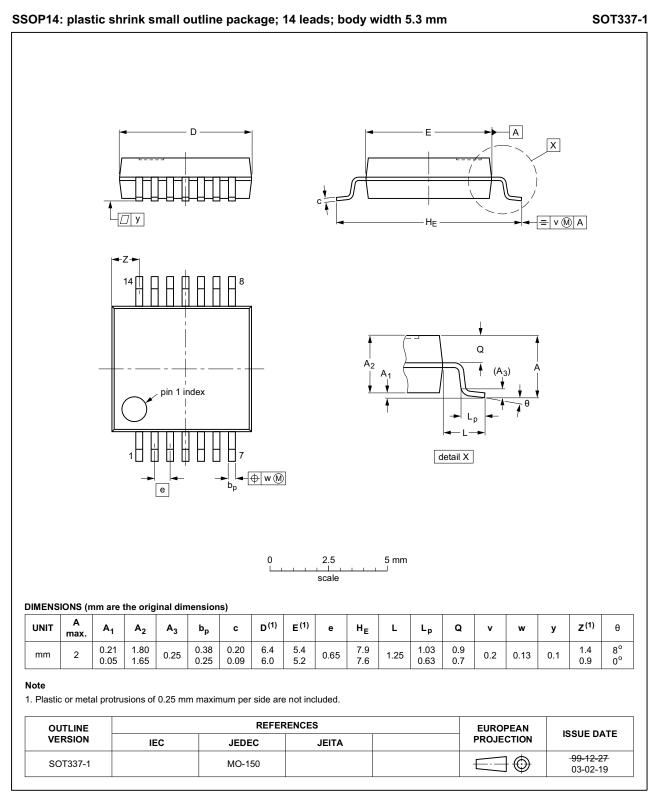
### 12. Package outline



### Fig 8. Package outline SOT108-1 (SO14)

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### Fig 9. Package outline SOT337-1 (SSOP14)

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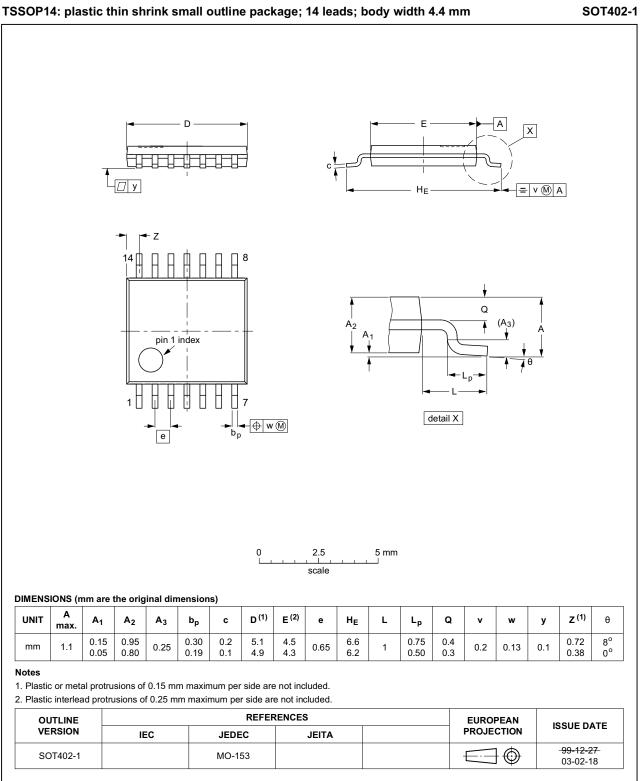


Fig 10. Package outline SOT402-1 (TSSOP14)

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### **13. Abbreviations**

Table 10. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal-Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

### 14. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT10 v.3	20160805	Product data sheet	-	74HC_HCT10_CNV v.2
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>			
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
74HC_HCT10_CNV v.2	19901201	Product specification	-	-

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions"

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